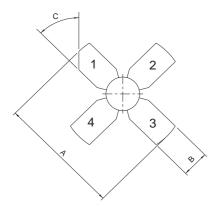
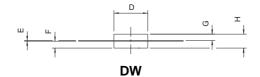


D1221UK

METAL GATE RF SILICON FET

MECHANICAL DATA





PIN 1 DRAIN PIN₂ SOURCE PIN₃ **GATE** PIN 4 SOURCE

DIM	mm	Tol.	Inches	Tol.
Α	26.16	0.38	1.030	0.015
В	5.72	0.13	0.225	0.005
O	45°	5°	45°	5°
ם	7.11	0.13	0.280	0.005
Е	0.13	0.03	0.005	0.001
F	1.52	0.13	0.055	0.005
G	0.43	0.20	0.060	0.008
Ι	7.67	REF	0.120	REF

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 10W - 12.5V - 175MHz SINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 10 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 175 MHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

$\overline{P_D}$	Power Dissipation	50W
BV_DSS	Drain – Source Breakdown Voltage	40V
BV_GSS	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	10A
T _{stg}	Storage Temperature	−65 to 150°C
T _j	Maximum Operating Junction Temperature	200°C

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Co	Min.	Тур.	Max.	Unit	
D\/	Drain-Source	V _{GS} = 0	I _D = 100mA	40			V
BV _{DSS}	Breakdown Voltage	v _{GS} = 0	ID = 100IIIX	40			V
_	Zero Gate Voltage	\/ 10 E\/	V 0			4	m ^
I _{DSS}	Drain Current	$V_{DS} = 12.5V$	$V_{GS} = 0$			1	mA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS} = 0			1	μΑ
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 1A	0.8			S
G _{PS}	Common Source Power Gain	P _O = 10W		10			dB
η	Drain Efficiency	V _{DS} = 12.5V	$I_{DQ} = 0.4A$	50			%
VSWR	Load Mismatch Tolerance	f = 175MHz		20:1			_
C _{iss}	Input Capacitance	$V_{DS} = 0$ V_{G}	_{iS} = -5V f = 1MHz			60	pF
C _{oss}	Output Capacitance	$V_{DS} = 12.5V V_{G}$	$_{iS} = 0$ $f = 1MHz$			40	pF
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 12.5V V_{G}$	$_{iS} = 0$ $f = 1MHz$		_	4	pF

^{*} Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

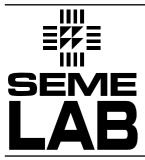
THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 3.5°C / W
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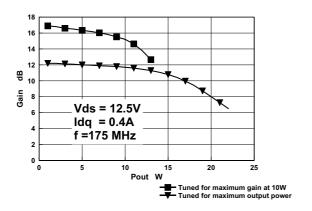


Figure 1 – Gain vs. Power Output.

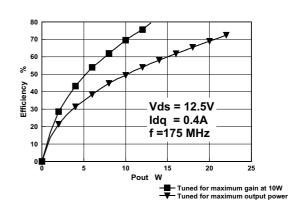


Figure 2 – Efficiency vs. Power Output.

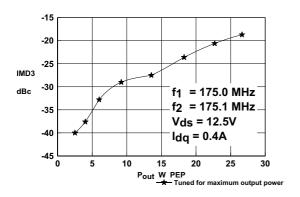


Figure 3 – IMD vs. Power Output.

D1221UK OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency MHz	Z _S Ω	Z_{L}		
175MHz	7.2 + j15	4.1 - j2.5		

Typical S Parameters

- $V_{DS} = 12.5V, I_{DQ} = 0.4A$
- MHZ S MA R 50

!Freq	!Freq S11		S21		S12		S22	
!MHz	mag	ang	mag	ang	mag	ang	mag	ang
50	0.7	-116.5	14.93	97.9	0.036	15.7	0.64	-108.4
100	0.7	-140	7.42	73.6	0.03	2.7	0.65	-132
150	0.75	-150.2	4.56	58.1	0.02	11	0.71	-143.1
200	0.81	-157.2	3.1	46.5	0.016	52.3	0.78	-151.2
250	0.85	-163.1	2.23	37.4	0.026	82.6	0.83	-157.9
300	0.88	-168.1	1.67	30.3	0.04	90.1	0.86	-163.7
350	0.9	-172.6	1.3	24.7	0.055	90.8	0.89	-168.8
400	0.92	-176.6	1.04	20.3	0.071	89.2	0.91	-173.4
450	0.93	179.7	0.85	17.1	0.086	86.8	0.92	-177.5
500	0.94	176.3	0.71	14.9	0.101	84.2	0.93	178.7
550	0.95	173.1	0.6	13.5	0.115	81.5	0.94	175.2
600	0.9!	170.	0.5%	13	0.1	78.	0.9!	171.

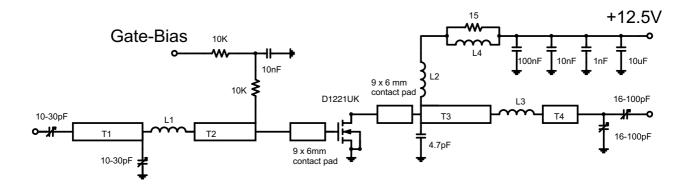
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Issue 1





Substrate 1.6mm PTFE/glass, Er=2.5

All microstrip lines W=4.4mm

- T1 10_{mm}
- T2 13mm
- T3 12mm
- T4 4mm
- L1 1.5 turns 22swg enamelled copper wire, 6mm i.d.
- L2 10 turns 19swg enamelled copper wire, 6mm i.d.
- L3 1.5 turns 22swg enamelled copper wire, 6mm i.d.
- L4 13.5 turns 19swg enamelled copper wire on Siemens B64920A618X830 ferrite core

D1221UK 175MHz TEST FIXTURE

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